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DESC FORM 193 SEP 87 *U.S. GOVERNMENT PRINTING OFFICE: 1987 - 748-129/60911

5962-E1098-1

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

1. SCOPE 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". 1.2 Part number. The complete part number shall be as shown in the following example: 5962-87001 Drawing number Device type Case outline Lead finish per (1.2.1)(1.2.2)MIL-M-38510 1.2.1 Device type. The device type shall identify the circuit function as follows: Device type Generic number Circuit function 01 10H536 Universal counter 1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows: Outline letter Case outline D-2 (16-lead, .840" x .310" x .200"), dual-in-line package F-5 (16-lead, .440" x .285" x .085"), flat package C-2 (20 terminal, .358" x .358" x .100"), square chip carrier package Ε F 2 1.3 Absolute maximum ratings. -8.0 V dc to 0.0 V dc -5.2 V dc to 0.0 V dc -65°C to +165°C +300°C Lead temperature (soldering, 10 seconds) - - - - -1.4 Recommended operating conditions. Supply voltage range (V_{EE}) - - - --5.46 V dc minimum to -4.94 V dc maximum $-55^{\circ}\mathrm{C}$ to $+125^{\circ}\mathrm{C}$ STANDARDIZED SIZE Α **MILITARY DRAWING** 5962-87001 **DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL** SHEET DAYTON, OHIO 45444 2

DESC FORM 193A SEP 87

± U. S. GOVERNMENT PRINTING OFFICE: 1988—550-547

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth tables. The truth tables shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
- 3.2.4 Test circuit and switching waveforms. The test circuit and switching waveforms shall be as pecified on figure 4.
 - 3.2.5 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

STANDARDIZED MILITARY DRAWING	SIZE A		59	62-87001	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	•	SHEET 3	

DESC FORM 193A SEP 87

Test	 Symbol 		Condit -55°C < TA unless otherw	< +125°C	£4.~	 Group A subgroups			Unit
Cases E, F, and 2		!.	Quiescent t		Tiea		Min	Max	<u> </u>
High level output voltage	V _{OH}	ter thr	puts minated ough	-0.650			-0.860	-0.780 -0.650	İ
Low level output voltage	V _{OL}	_ \	Ω to -2.0 V = -5.2 V = 0.0 V	-0.840 -0.780 -0.650 -0.840	-1.950 -1.950	1 2	-1.950 -1.950	-0.840 -1.580 -1.565 -1.610	V
High level threshold output voltage	V _{OHA}	_ _		-1.110 -0.960 -1.160	 -1.480 -1.465	1 1	-1.010 -0.860	-0.780 -0.650 -0.840	V
Low level threshold output voltage	V _{OLA}			-1.110 -0.960 -1.160	-1.465	2	-1.950	 -1.580 -1.565 -1.610	Ì
Power supply drain current <u>3</u> /	I IEE	1 Vc	E = -5.46 V C = 0.0 V H = -0.780 V at -0.650 V at 0.840 V at	: +125°C			-150 -165		mA
High level input current	IIH	- 		Carry		1,2		240 380	μА
		 		D ₀ , D ₁ D ₂ , D ₃ Clock	•	1,2		275 430	μА
				S ₂		1,2 3		335 535	μ A
				s ₁		1,2 3		420 670	μА
Low level input current	IIL	I VTI	= -4.94 V = -1.950 V = 0.0 V	<u>3</u> /		1,3	0.5	! ! !	μА
Functional tests		See	4.3.1c	, ,		7,8	İ		
ee footnotes at end of tabl									
STANDARDIZEI MILITARY DRAW			SIZE A		ŀ	5962	2-87001		
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查询"5962-87001012X"供店 TABLE 1	<u>Electri</u>	ical pe	erformance	chara	cterist	tics - Co	ontinued.			
Test	 Symbol		Cor -55°C <	ditio	ns +125°C		 Group A subgroups	Lim		Unit
	<u> </u>	<u> </u>	unless off	erwis	e speci	fied	<u> </u>	Min	Max	
Cases E and F			DC rapi	d tes	ts <u>4</u> /	•	·	T*		
High level output voltage	l Vari	 Outp	ute	! 	ν _{IH}	VIL	 	1 	! 	
night level output voitage	I VOH	term thro 100Ω	inated ugh to -2 V	ĺ	-0.819 -0.692 -0.882		1 2 3		-0.819 -0.692 -0.882	
Low level output voltage	V _{OL}	VCC VEE 27	= 0.0 V = -5.2 V	- 1	-0.819 -0.692 -0.882	-1.950	1 1 2 1 3		-1.592 -1.578 -1.623	
High level threshold output voltage	V _{OHA}	_ -		j	-1.146 -0.999 -1.199	1-1.478	1 2 3		-0.819 -0.692 -0.822	
Low level threshold output voltage	VOLA			ĺ	-1.146 -0.999 -1.199	1-1.478	1 2 3	-1.950	 -1.592 -1.578 -1.623	
Power supply drain current 3/	I IEE	VCC	= -5.46 V = 0.0 V = -0.780 -0.650 -0.840	V at V at	+125 C		1 2,3 	 -149 -164 	 	mA
High level input current	IIH	- <u> </u> 	-0.040	7 at	Carry	in	1,2	i I	225 365	μА
	 				D ₀ , D ₁ D ₂ , D ₃ Clock	,	1,2		260 415	μА
]	s ₂		1,2	 	320 520	μА
	 				s ₁	-	1,2	 	405 655	μА
Low level input current	IIL	VTI	= -4.94 \ = -1.950 = 0.0 V	v <u>3</u>	/		1,3	0.5		μА
Functional tests		See	4.3.1c				7,8	 	 	
See footnotes at end of tab	ole.									
STANDARDIZE MILITARY DRAV			SIZE A				59	62-8700	1	
DEFENSE ELECTRONICS SU DAYTON, OHIO 45	PPLY CENTE	R			REVISK	ON LEVEL		SHEET	5	

Test	 Symbol 		-55°C <	nditi TA ≤	+125°C	£1.J	 Group A subgroups			Un
Case 2	<u> </u>	1	unless ot DC rap		se speci sts <u>4</u> /		1	<u> Min</u>	Max	<u> </u>
High level output voltage	У ОН	ter	puts minated	- "	V _{IH} -0.818 -0.692		:		 -0.818 -0.692	
Low level output voltage	V _{OL}	_ 100	α to -2 V = 0.0 V = -5.2 V		-0.882 -0.818 -0.692 -0.882	-1.950 -1.950	3 1 1 2	-1.098 -1.950 -1.950	-0.882 -1.592 -1.578 -1.623	 - \
High level threshold output voltage	V _{OHA}				-1.145 -0.998 -1.198	1-1.478	1 2 3	-0.898	-0.818 -0.692 -0.882	ĺ
Low level threshold output voltage	VOLA				-1.145 -0.998 -1.199	1-1.478		-1.950 -1.950	-1.592 -1.578 -1.623	l V
Power supply drain current <u>3</u> /	IEE	VE	E = -5.46 V C = 0.0 V H = -0.780 -0.650 -0.840	V at V at	+125°C			-149 -164		m/
High level input current	IIH	- 			Carry i	in	1,2		225 365	μА
!				 	D ₀ , D ₁ , D ₂ , D ₃ , Clock	,	1,2		260 415	μА
				 	S2		1,2	 	320 520	μА
		 		 	s ₁		1,2		405 655	μА
Low level input current	IIL	I VII	= -4.94 V = -1.950 = 0.0 V	V <u>3</u>	/	 	1,3	0.5 0.3	 	μА
Functional tests		See	4.3.1c		 		7,8			
ee footnotes at end of table STANDARDIZE			SIZE							
MILITARY DRAW DEFENSE ELECTRONICS SUPP	- -		<u> </u>			N LEVEL	5962	2-87001		

DESC FORM 193A SEP 87

★ U. S. GOVERNMENT PRINTING OFFICE: 1988—549-904

	[Unit	
Test	Symbol 	-55°C <	onditions T _{A <} +125°C herwise specified	Group A subgroups		mits Max	
Cases E, F, and 2			C tests				
Transition time low to high or high to low	t _{TLH} ,	V _{EE} = -2.94 V _{CC} = 2.0 V C _I < 5 pF	V tputs through	9 10,11	0.7	2.1	ns
Propagation delay time, CLOCK high to Q _O high or low	tpHH1,	Lōad all ou 100Ω to gro See figure 	und	9 10,11	0.7	3.2	ns
Propagation delay time, CLOCK high to CARRY OUT high or low	tpHH2,			9 10,11	0.7	7.0	ns
Propagation delay time, CARRY IN high to CARRY OUT high	 t РНН3 			9 10,11	0.7	3.0	ns
Propagation delay time, CARRY IN low to CARRY OUT low	 tp _{LL} 			9 10,11	0.7	3.0	 ns
Maximum count frequency	f _{MAX}	 		9,10,11	 250 		 MH
Setup time, D _O high or low to CLOCK high	t _{S1}	 		9,10,11	2.0		l ns
Setup time, S ₁ or S ₂ high to CLOCK high	t _{S2}	 		9,10,11	3.5		l ns
Setup time, CARRY IN low to CLOCK high	t _{S3}	 		9,10,11	2.0		 ns
Setup time, CLOCK high to CARRY IN high	t _{S4}	 		9,10,11	0.0	 	ns
Hold time, CLOCK high to D _O high or low	t _{H1}	 		9,10,11	0.0		l ns
Hold time, CLOCK high to S ₁ or S ₂ high	t _{H2}	 		9,10,11	-0.5		l ns
Hold time, CLOCK high to CARRY IN low	4 н3	 		9,10,11	150		l ps
Hold time, CARRY IN high to CLOCK high ee footnotes on next page.	 t _{H4} 			9 10,11	2.0		 ns
		SIZE					
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- 1/ The quiescent limits are determined after a device has reached thermal equilibrium. This is defined as the reading taken with the device in a socket with > 500 LFPM of +25°C, +125°C or -55°C (as applicable) air blowing on the unit in a transverse direction with power applied for at least four (4) minutes before the reading is taken. This method was used for theoretical limit establishment only. All devices shall be tested to the delta V (rapid test) conditions specified herein. The rapid test method is an equivalent method of testing quiescent conditions.
- 2/ The high and low level output current varies with temperature, and shall be calculated using the following formulas:

 $\begin{array}{l} I_{OH} = \left(\begin{smallmatrix} V_{OH} & - & 2 & V \end{smallmatrix} \right) / 100 \Omega \\ I_{OL} = \left(\begin{smallmatrix} V_{OL} & - & 2 & V \end{smallmatrix} \right) / 100 \Omega \\ \end{array}$

- 3/ The IEE and III limits, although specified in the minimum column, shall not be exceeded in magnitude, as a maximum value.
- 4/ The dc rapid test forcing functions and limits are used for all dc testing. These limits are determined for each device type based on the power dissipation and package type. The rapid test (delta V) limits and forcing functions are skewed allowing rapid testing to be performed at standard temperatures without the addition of delta T's.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-SID-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-SID-883 including groups A, B, C, and D inspections. The following additional criteria shall apply:

STANDARDIZED MILITARY DRAWING	SIZE A		5	962-87001	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL		SHEET 8	

DESC FORM 193A

SEP 87

± U. S. GOVERNMENT PRINTING OFFICE: 1988--549-904

Case outlines	 E 	F	2 2				
Terminal number	l Term	inal symbol					
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20	VCC1 Q2 Q3 CARRY OUT D3 D2 S2 VEE S1 CARRY IN D1 D0 CLOCK Q0 Q1 VCC2	CLOCK Q0 Q1 VCC2 VCC1 Q2 Q3 CARRY OUT D3 D2 S2 VEE SI CARRY IN D1 D0	NC VCC1 Q2 Q3 CARRY OUT NC D3 D2 S2 VEE NC S1 CARRY IN D1 D0 NC CLOCK Q0 Q1 VCC2				

NC = No connection

FIGURE 1. Terminal connections.

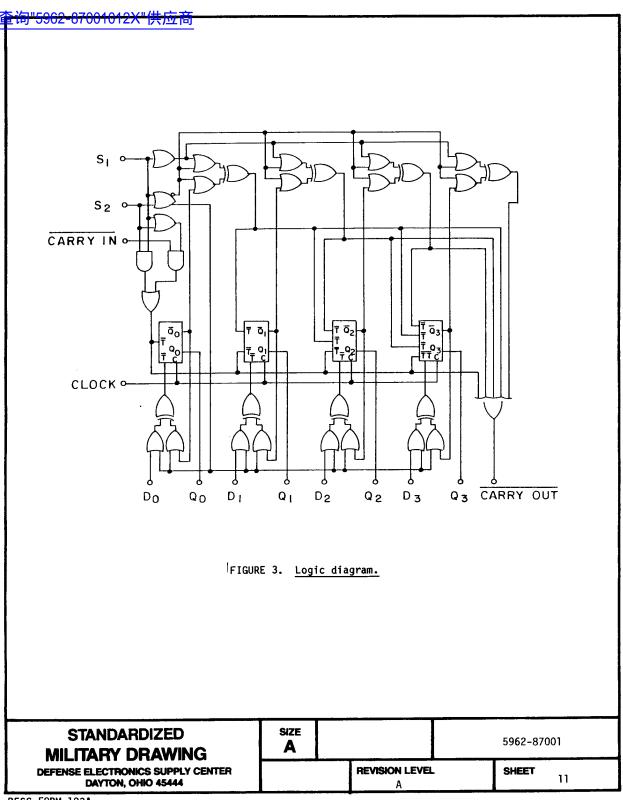
STANDARDIZED
MILITARY DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

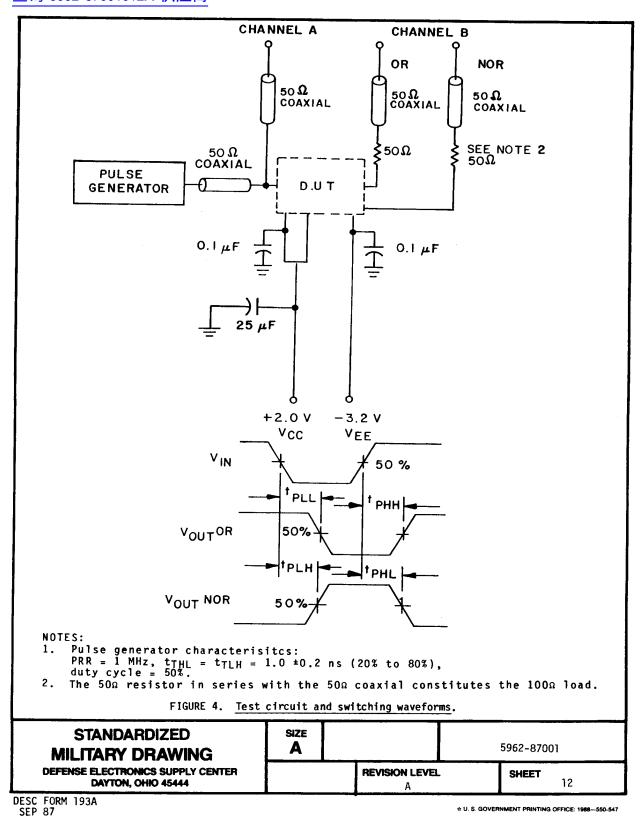
DESC FORM 193A SEP 87

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				T	Н		. Н	 Ho1d	cou	nt								
				T	L		1 L	Count	do	wn		1	-					
				T	Н		1 L	Hold (cou	nt		1	-					
				1	Х	}	1 H	 Stop (c ou	nt		- - -	-					
	<u>.</u>																	
				In	puts					C	utp	uts						
	S ₁	S2	D _O	D ₁	 D2 	D3	CARRY IN	CLOCK	 Q ₍	Q1	Q2	 Q3	CARRY					
	 L L L	 H H H	IL IX IX	IL IX IX IX			X L L	 H H H	L H L H	IL IL IH	 H H H	 H H H	L H H					
	IL IL IH IL		X	X X		X I	H H X	 L H H	 H H H		 H H H	 H	H H H					
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87001012X"供应商 TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*,2,3,7*,8,9
Group A test requirements (method 5005)	l 1,2,3,7,8,9, 10,11
Groups C and D end-point electrical parameters (method 5005)	1,2,3

^{*}PDA applies to subgroups 1 and 7.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 7 and 8 tests shall verify the truth table as specified on figure 2 herein.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by and method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

STANDARDIZED MILITARY DRAWING	SIZE A			59	962-87001	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		F	REVISION LEVEL A		SHEET 13	

DESC FORM 193A SEP 87

± U. S. GOVERNMENT PRINTING OFFICE: 1988--550-547

6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

6.4 <u>Approved source of supply</u>. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number 1/
5962-8700101EX	04713	10H536/BEAJC
5962-8700101FX	04713	10H536/BFAJC
5962-87001012X	04713	10H536M/B2AJC

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number 04713

Vendor name and address

Motorola, Incorporated 7402 S. Price Road Tempe, AZ 85283

STANDARDIZED
MILITARY DRAWING

DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444

SIZE A 5962-87001

REVISION LEVEL SHEET A 14

DESC FORM 193A SEP 87

± U. S. GOVERNMENT PRINTING OFFICE: 1988—550-547

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